

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







LQA06T300 Qspeed[™] Family

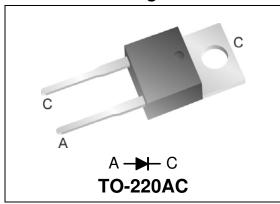


300 V, 6 A Q-Series Diode

Product Summary

I _{F(AVG)}	6	Α
V_{RRM}	300	V
Q _{RR} (Typ at 125 °C)	27	nC
I _{RRM} (Typ at 125 °C)	1.87	Α
Softness t _b /t _a (Typ at 125 °C)	0.7	

Pin Assignment



RoHS Compliant

Package uses Lead-free plating and "Green" mold compound Halogen free per IEC 61249-2-21.

General Description

This device has the lowest Q_{RR} of any 300 V Silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- AC/DC and DC/DC output rectification
 - · Output & freewheeling diodes
- · Motor control drive circuits
- Uninterruptible Power Supply (UPS) inverters

Features

- \bullet Low $Q_{RR},$ Low $I_{RRM},$ Low t_{RR}
- High dl_F/dt capable (1000A/μs)
- · Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- Enables extremely fast switching

Absolute Maximum Ratings

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V_{RRM}	Peak repetitive reverse voltage		300	V
I _{F(AVG)}	Average forward current	T _J = 150 °C, T _C = 117°C	6	Α
I _{FSM}	Non-repetitive peak surge current	60 Hz, ½ cycle	37	Α
I _{FSM}	Non-repetitive peak surge current	$\frac{1}{2}$ cycle of T = 28 us Sinusoid, $T_C = 25$ °C	350	Α
TJ	Maximum junction temperature		150	°C
T _{STG}	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6mm from case, 10 sec	300	°C
P _D	Power dissipation	T _C = 25 °C	33.8	W
V_{RRM}	Peak repetitive reverse voltage		300	V

Thermal Resistance

Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JA}$	Junction to ambient	TO-220	62	°C/W
$R_{\theta JC}$	Junction to case	TO-220	3.7	°C/W

www.powerint.com January 2011

Electrical Specifications at T_J= 25 °C (unless otherwise specified)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DC Chara	acteristics	•					
I _R	Reverse current	$V_R = 300 \text{ V}, T_J = 300 \text{ V}$	25 °C	-	-	25	μΑ
		V _R = 300 V, T _J = 125 °C		-	0.24	-	mA
V _F	Forward voltage	I _F = 6 A, T _J = 25 °C		-	1.6	1.9	V
		$I_F = 6 A, T_J = 150$	°C	-	1.34	-	V
CJ	Junction capacitance	V _R = 10 V, 1 MHz		-	19	-	pF
Dynamic	Characteristics						
t _{RR}	Reverse recovery time,	dI _F /dt =200A/μs	T _J =25 °C	-	11.5	-	ns
		V _R =200V, I _F =6A	T _J =125 °C	-	21	-	ns
Q _{RR}	Reverse recovery charge,	dI _F /dt =200A/μs	T _J =25 °C	-	8.5	13	nC
		$V_R=200V$, $I_F=6A$	T _J =125 °C	-	27	-	nC
I _{RRM}	Maximum reverse	dI _F /dt =200A/μs	T _J =25 °C	-	1.15	1.6	Α
	recovery current,	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	T _J =125 °C	-	1.87	-	Α
S	t _h	dI _F /dt =200A/μs	T _J =25 °C	-	0.7	-	
	Softness = $\frac{t_b}{t_a}$		T _J =125 °C	-	0.7	-	

<u>Note to component engineers</u>: Q-series diodes employ Schottky technologies in their design and construction. Therefore, component engineers should plan their test setups to be similar to traditional Schottky test setups. (For further details, see application note AN-300.)

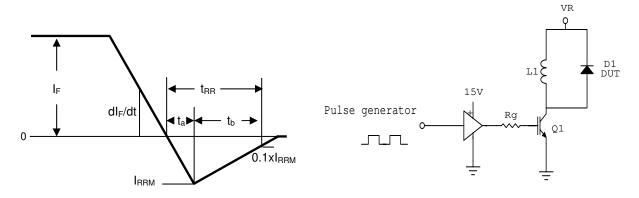


Figure 1. Reverse Recovery Definitions

Figure 2. Reverse Recovery Test Circuit

Electrical Specifications at T_J= 25 °C (unless otherwise specified)

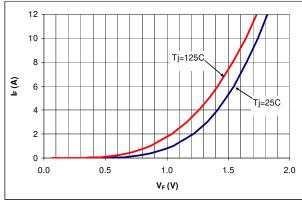


Figure 3. Typical I_{F} vs V_{F}

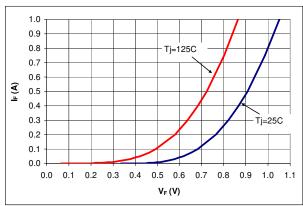


Figure 4. Typical I_F vs V_F

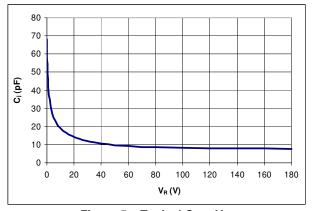


Figure 5. Typical C_i vs V_R

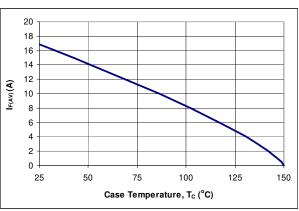


Figure 6. DC Current Derating Curve

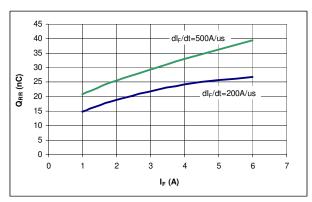


Figure 7. Typical Q_{RR} vs I_F at T_i =125 °C

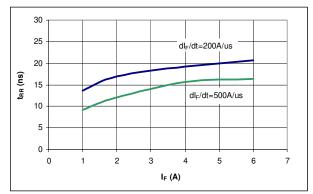
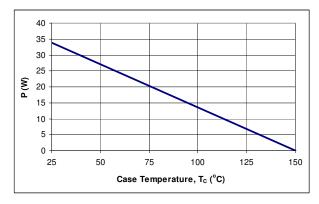


Figure 8. Typical t_{RR} vs I_F at T_i =125 °C



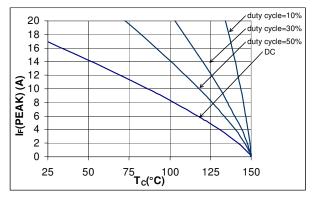


Figure 9. IF(PEAK) vs TC, f=70 kHz

Figure 10. IF(PEAK) vs TC, f=70 kHz

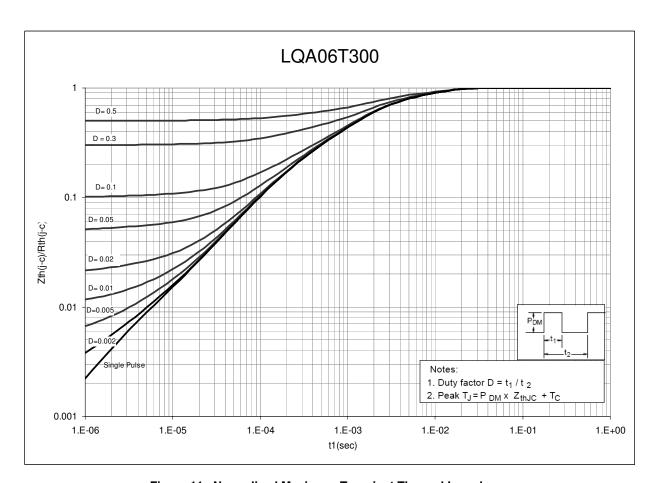
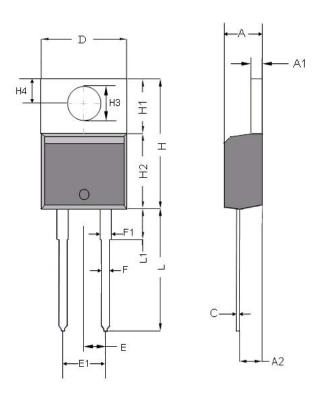


Figure 11. Normalized Maximum Transient Thermal Impedance

Dimensional Outline Drawings



	Millimeters		
Dim	MIN	MAX	
Α	4.32	4.70	
A 1	1.14	1.40	
A 2	2.03	2.79	
С	0.34	0.610	
D	9.65	10.67	
Е	2.49	2.59	
E 1	4.98	5.18	
F	0.508	1.016	
F1	1.14	1.78	
Н	14.71	16.51	
H1	5.84	6.55	
H2	8.51	9.25	
Н3	3.53	3.96	
H4	2.54	3.05	
L	12.70	14.22	
L1	-	6.35	

Mechanical Mounting Method	Maximum Torque / Pressure specification	
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)	
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm²) or 175 lbf/in²	

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
LQA06T300	TO-220AC	50 units/tube

The information contained in this document is subject to change without notice.



LQA06T300

Revision	Notes	Date
1.1	Released by Qspeed	05/09
1.2	Converted to Power Integrations Document	01/11



For the latest updates, visit our website: www.powerint.com

Power Integrations reserves the right to make changes to its products at any time to improve reliability or manufacturability. Power Integrations does not assume any liability arising from the use of any device or circuit described herein. POWER INTEGRATIONS MAKES NO WARRANTY HEREIN AND SPECIFICALLY DISCLAIMS ALL WARRANTIES INCLUDING, WITHOUT LIMITATION, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF THIRD PARTY RIGHTS.

PATENT INFORMATION

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/. Power Integrations grants its customers a license under certain patent rights as set forth at https://www.powerint.com/.

The PI Logo, TOPSwitch, TinySwitch, LinkSwitch, DPA-Switch, PeakSwitch, CAPZero, SENZero, LinkZero, HiperPFS, HiperTFS, Qspeed, EcoSmart, Clampless, E-Shield, Filterfuse, StackFET, PI Expert and PI FACTS are trademarks of Power Integrations, Inc. Other trademarks are property of their respective companies. ©Copyright 2011 Power Integrations, Inc.

Power Integrations Worldwide Sales Support Locations

WORLD HEADQUARTERS

5245 Hellyer Avenue San Jose, CA 95138, USA. Main: +1-408-414-9200 Customer Service: Phone: +1-408-414-9665 Fax: +1-408-414-9765

e-mail:

usasales@powerint.com

CHINA (SHANGHAI) Rm 1601/1610, Tower 1

Kerry Everbright City No. 218 Tianmu Road West Shanghai, P.R.C. 200070 Phone: +86-021-6354-6323 Fax: +86-021-6354-6325 e-mail: chinasales@powerint.com

CHINA (SHENZHEN)

Rm A, B & C 4th Floor, Block C, Electronics Science and Technology Building 2070 Shennan Zhong Road Shenzhen, Guangdong, P.R.C. 518031 Phone: +86-755-8379-3243

Fax: +86-755-8379-5828

e-mail:

chinasales@powerint.com

GERMANY

Rueckertstrasse 3 D-80336, Munich Germany Phone: +49-89-5527-3911 Fax: +49-89-5527-3920

e-mail:

eurosales@powerint.com

INDIA

#1, 14th Main Road Vasanthanagar Bangalore-560052 India Phone: +91-80-4113-8020 Fax: +91-80-4113-8023 e-mail: indiasales@powerint.com

ITALY

Via De Amicis 2 20091 Bresso MI Italy Phone: +39-028-928-6000 Fax: +39-028-928-6009 e-mail: eurosales@powerint.com

JAPAN

Kosei Dai-3 Building 2-12-11, Shin-Yokohama, Kohoku-ku, Yokohama-shi, Kanagawa 222-0033 Japan

Japan

Phone: +81-45-471-1021 Fax: +81-45-471-3717

e-mail: japansales@powerint.com

KOREA

RM 602, 6FL Korea City Air Terminal B/D, 159-6 Samsung-Dong, Kangnam-Gu, Seoul, 135-728 Korea

Phone: +82-2-2016-6610 Fax: +82-2-2016-6630

e-mail: koreasales@powerint.com

SINGAPORE

51 Newton Road, #19-01/05 Goldhill Plaza Singapore, 308900 Phone: +65-6358-2160 Fax: +65-6358-2015 e-mail:

singaporesales@powerint.com

TAIWAN

5F, No. 318, Nei Hu Rd., Sec. 1 Nei Hu District Taipei 114, Taiwan R.O.C. Phone: +886-2-2659-4570 Fax: +886-2-2659-4550 *e-mail*:

taiwansales@powerint.com

EUROPE HQ

1st Floor, St. James's House East Street, Farnham Surrey GU9 7TJ United Kingdom Phone: +44 (0) 1252-730-141 Fax: +44 (0) 1252-727-689 e-mail: eurosales@powerint.com

APPLICATIONS HOTLINE World Wide +1-408-414-9660

APPLICATIONS FAX
World Wide +1-408-414-9760

